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# Oxide-based Materials and Devices XIII

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## Contents

#### vii Conference Committee

#### PLASMONICS

12002 02	Semiconductor plasmonics and metamaterials for IR applications (Invited Paper) [12002-1]			
12002 03	Coupling of localized surface plasmons to intersubband transitions in CdO/GaAs (Invited Paper) [12002-2]			
12002 04	Electrochromic photonic devices for nanoplasmonic transmission modulation [12002-4]			
	GA2O3: ATOMIC SCALE DEFECTS, DEEP LEVELS/DOPING, AND GROWTH I			
12002 05	Growth and defect characterization of doped and undoped $\beta$ -Ga <sub>2</sub> O <sub>3</sub> crystals [12002-10]			
	GA2O3: ATOMIC SCALE DEFECTS, DEEP LEVELS/DOPING, AND GROWTH II			
12002 06	Conduction properties and threshold voltage instability in $\beta$ -Ga <sub>2</sub> O <sub>3</sub> MOSFETs [12002-16]			
12002 07	Effect of high-energy electron irradiation on the electronic properties of $\beta$ -gallium oxide (Invited Paper) [12002-60]			
	GA2O3: TOWARD APPLICATIONS			
12002 08	Ultralow-power deep-ultraviolet photodetection using oxide-nitride heterojunctions integrated on silicon [12002-25]			
12002 09	Deep levels and conduction processes in nitrogen-implanted Ga <sub>2</sub> O <sub>3</sub> Schottky barrier diodes [12002-11]			
12002 0A	Ga <sub>2</sub> O <sub>3</sub> microwires as wide dynamical range temperature sensors (Invited Paper) [12002-26]			

#### GA<sub>2</sub>O<sub>3</sub>: MODELING AND THEORETICAL STUDIES

12002 0B First-principles studies of diffusion in gallium oxide (Invited Paper) [12002-28]

#### NOVEL APPROACH FOR GROWTH

- 12002 0C Sputtering platform for double-sided precision optical coatings [12002-40]
- 12002 0D Study of rotary atomic layer deposition for optical applications [12002-41]

#### **FUNCTIONAL OXIDES**

- 12002 OE Enhanced nonlinear optics in nanowires, waveguides, and ring resonators integrated with graphene oxide films [12002-32]
- 12002 OF Synthesis and characterization of semiconducting oxide nanoparticles and hybrid composites with energy-related applications (Invited Paper) [12002-37]
- 12002 0G Investigation of dynamic optical processes of tapered silicon pillars (Invited Paper) [12002-57]

#### **ZNO AND MGZNO**

12002 OH	Structural properties and absorption band edge tunability in ZnMnO by metal-organic chemical vapor deposition and atomic layer deposition (Invited Paper) [12002-43]
12002 01	Polarization-resolved photoluminescence study of an atom probe tip containing a ZnO- (Mg,Zn)O heterostructure (Invited Paper) [12002-44]
12002 OJ	Nanostructures wetting evaluation using ultra high frequency ultrasound (Invited Paper) [12002-58]
12002 OK	Investigation of transition metal-doped zinc oxide for spintronics (Invited Paper) [12002-64]

#### PIEZO- AND DI-ELECTRIC OXIDES

- 12002 OL Second harmonic generation in multiferroic BaTiO3-BiFeO3 film and nanorod arrays grown on Si substrate (Invited Paper) [12002-48]
- 12002 0M Fully CMOS-compatible pyroelectric infrared detector based on doped HfO2 thin film in 3D-integration [12002-49]

#### POSTER SESSION

12002 ON	Electron plasma	parameters of oxide-based silve	r crystals	[12002-50]
----------	-----------------	---------------------------------	------------	------------

- 12002 00 Metal oxide nanoparticles incorporated mesoporous silica nanospheres for oxygen scavenging [12002-51]
- 12002 OP Characterizations of tin oxide thin films prepared by different methods for perovskite solar cell applications [12002-52]

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